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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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Not recommended
for new design

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2SK3234

Silicon N Channel MOS FET
High Speed Power Switching

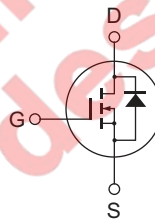
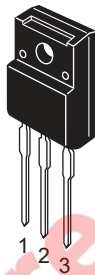
REJ03G1097-0200
(Previous: ADE-208-1370)
Rev.2.00
Sep 07, 2005

Features

- Low on-resistance: $R_{DS(on)} = 0.65 \Omega$ typ.
- Low leakage current: $I_{DSS} = 1 \mu A$ max (at $V_{DS} = 500 V$)
- High speed switching: $t_f = 25 ns$ typ (at $V_{GS} = 10 V$, $V_{DD} = 250 V$, $I_D = 4 A$)
- Low gate charge: $Q_g = 25 nC$ typ (at $V_{DD} = 400 V$, $V_{GS} = 10 V$, $I_D = 8 A$)
- Avalanche ratings

Outline

RENESAS Package code: PRSS0003AE-A
(Package name: TO-220C*FM)



1. Gate
2. Drain
3. Source

Absolute Maximum Ratings

(Ta = 25°C)

| Item | Symbol | Value | Unit |
|---|---|-------------|------|
| Drain to source voltage | V _{DSS} | 500 | V |
| Gate to source voltage | V _{GSS} | ±30 | V |
| Drain current | I _D | 8 | A |
| Drain peak current | I _{D (pulse)} ^{Note 1} | 32 | A |
| Body-drain diode reverse drain current | I _{DR} | 8 | A |
| Body-drain diode reverse drain peak current | I _{DR (pulse)} ^{Note 1} | 32 | A |
| Avalanche current | I _{AP} ^{Note 3} | 8 | A |
| Channel dissipation | P _{ch} ^{Note 2} | 35 | W |
| Channel to case thermal impedance | θ _{ch-c} | 3.57 | °C/W |
| Channel temperature | T _{ch} | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

- Notes: 1. PW ≤ 10 ∞s, duty cycle ≤ 1%
 2. Value at T_c = 25°C
 3. T_{ch} ≤ 150°C

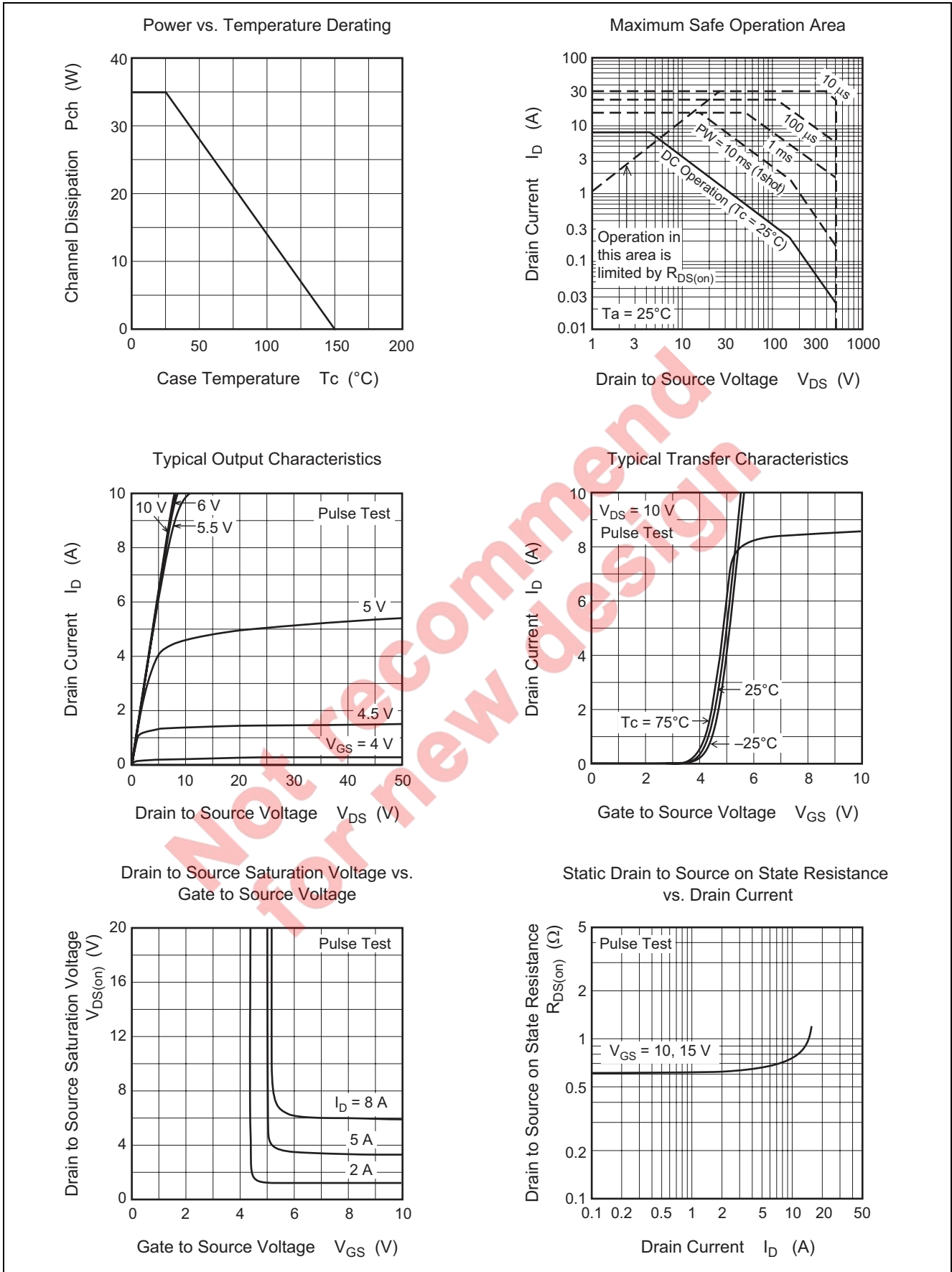
Electrical Characteristics

(Ta = 25°C)

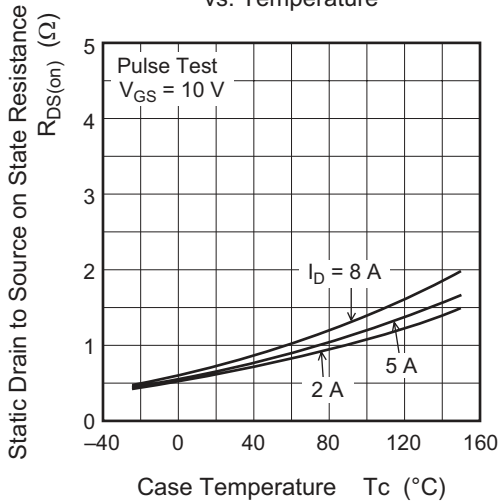
| Item | Symbol | Min | Typ | Max | Unit | Test Conditions |
|--|-----------------------|-----|------|------|------|--|
| Drain to source breakdown voltage | V _{(BR) DSS} | 500 | — | — | V | I _D = 10 mA, V _{GS} = 0 |
| Gate to source leak current | I _{GSS} | — | — | ±0.1 | ∞A | V _{GS} = ±30 V, V _{DS} = 0 |
| Zero gate voltage drain current | I _{DSS} | — | — | 1 | ∞A | V _{DS} = 500 V, V _{GS} = 0 |
| Gate to source cutoff voltage | V _{GS (off)} | 3.0 | — | 4.0 | V | I _D = 1 mA, V _{DS} = 10 V |
| Static drain to source on state resistance | R _{DS (on)} | — | 0.65 | 0.85 | Ω | I _D = 4 A, V _{GS} = 10 V ^{Note 4} |
| Forward transfer admittance | y _{fs} | 4.0 | 7.0 | — | S | I _D = 4 A, V _{DS} = 10 V ^{Note 4} |
| Input capacitance | C _{iss} | — | 970 | — | pF | V _{DS} = 25 V |
| Output capacitance | C _{oss} | — | 110 | — | pF | V _{GS} = 0 |
| Reverse transfer capacitance | C _{rss} | — | 18 | — | pF | f = 1 MHz |
| Turn-on delay time | t _{d (on)} | — | 25 | — | ns | I _D = 4 A |
| Rise time | t _r | — | 21 | — | ns | V _{GS} = 10 V |
| Turn-off delay time | t _{d (off)} | — | 80 | — | ns | R _L = 62.5 Ω |
| Fall time | t _f | — | 25 | — | ns | R _g = 10 Ω |
| Total gate charge | Q _g | — | 25 | — | nC | V _{DD} = 400 V |
| Gate to source charge | Q _{gs} | — | 4 | — | nC | V _{GS} = 10 V |
| Gate to drain charge | Q _{gd} | — | 11 | — | nC | I _D = 8 A |
| Body-drain diode forward voltage | V _{DF} | — | 0.9 | 1.35 | V | I _F = 8 A, V _{GS} = 0 |
| Body-drain diode reverse recovery time | t _{rr} | — | 360 | — | ns | I _F = 8 A, V _{GS} = 0 |
| Body-drain diode reverse recovery charge | Q _{rr} | — | 1.7 | — | ∞C | di _F /dt = 100 A/∞s |

Note: 4. Pulse test

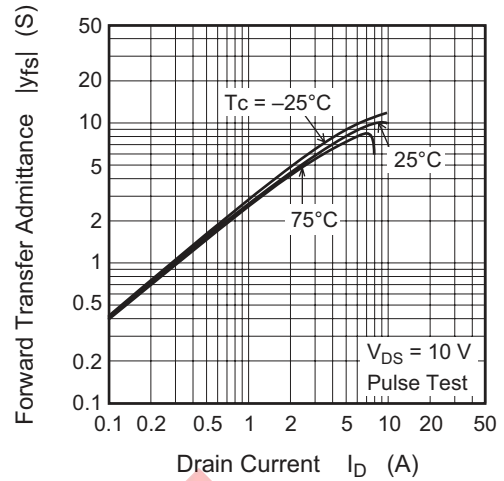
Main Characteristics



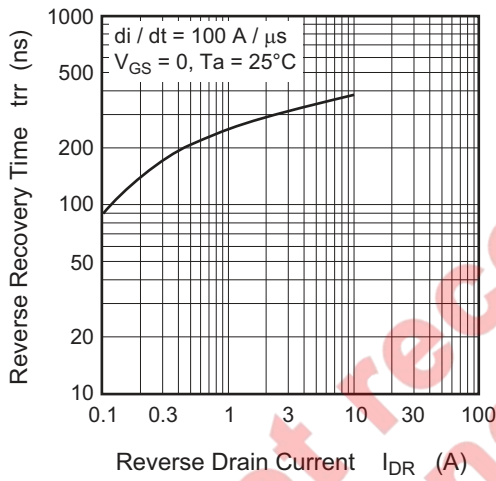
Static Drain to Source on State Resistance vs. Temperature



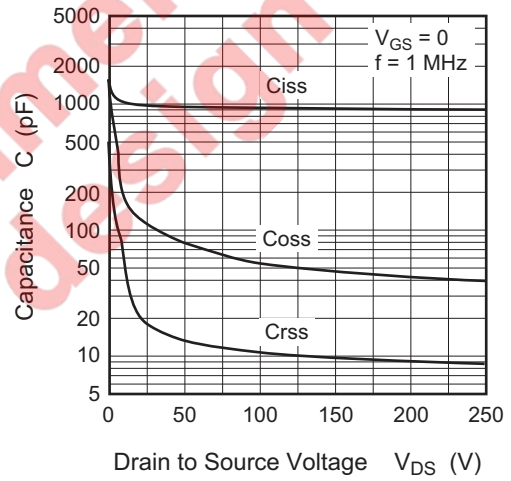
Forward Transfer Admittance vs. Drain Current



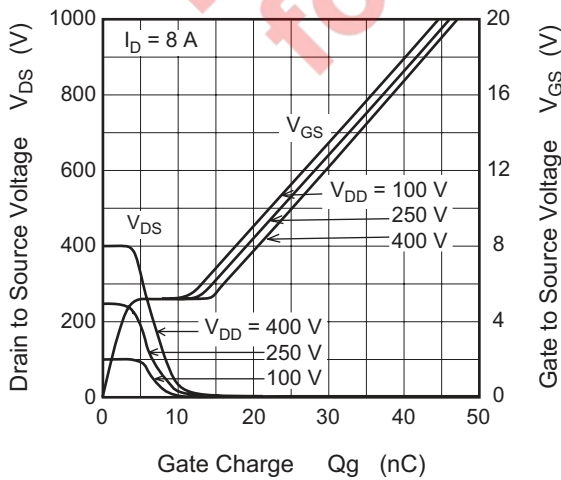
Body-Drain Diode Reverse Recovery Time



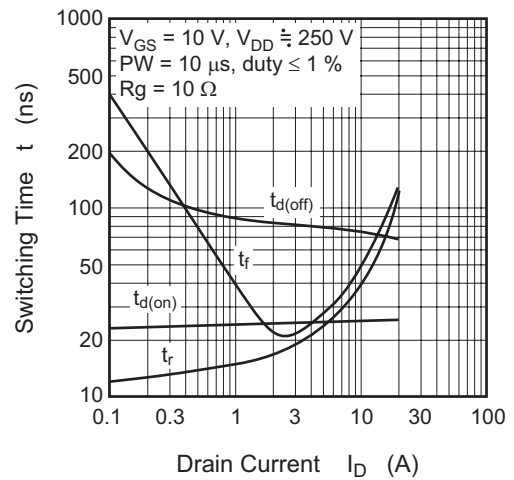
Typical Capacitance vs. Drain to Source Voltage



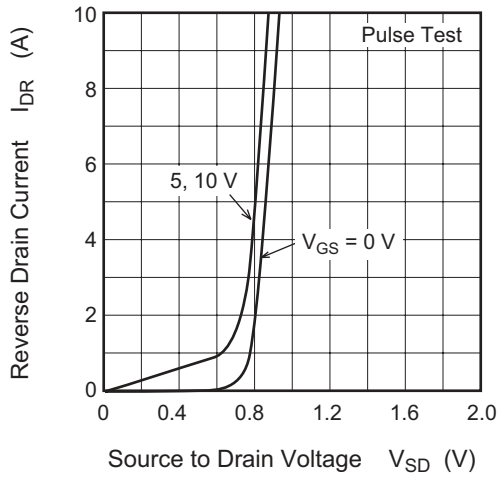
Dynamic Input Characteristics



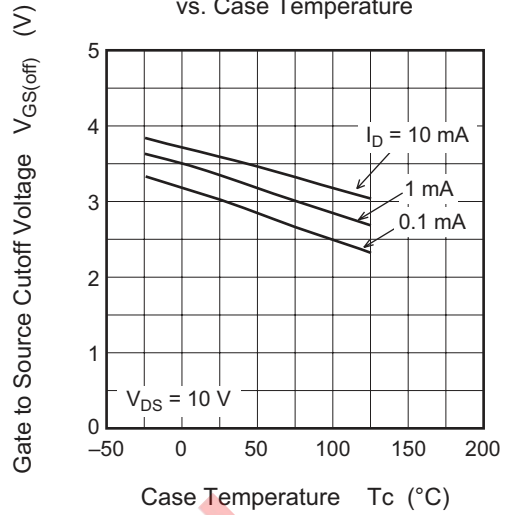
Switching Characteristics



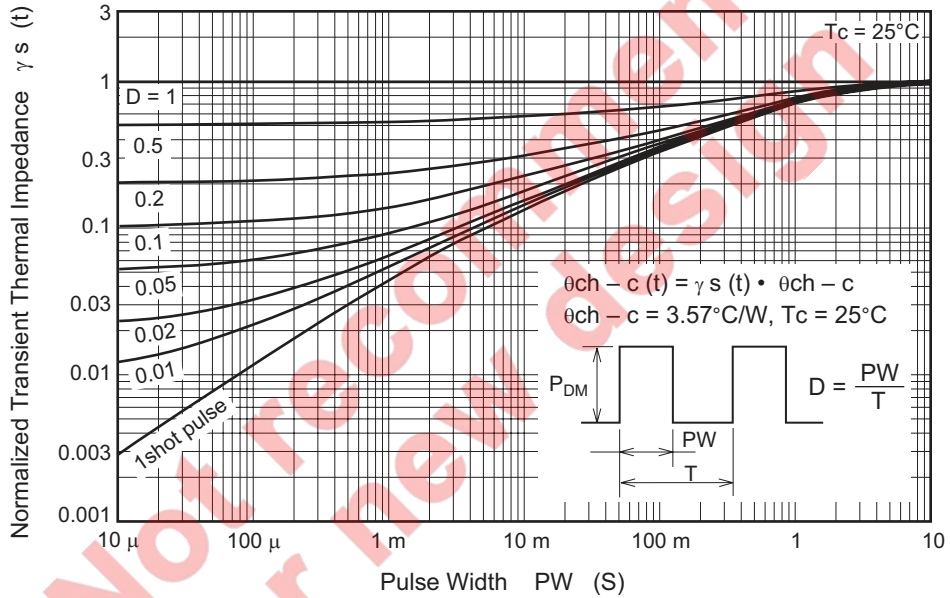
Reverse Drain Current vs. Source to Drain Voltage



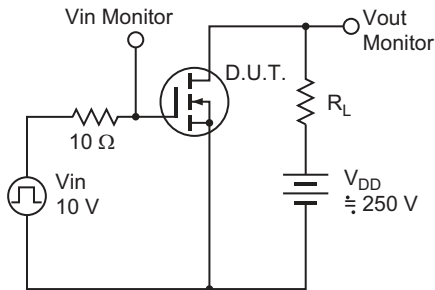
Gate to Source Cutoff Voltage vs. Case Temperature



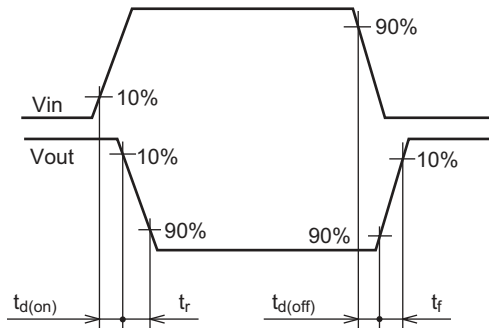
Normalized Transient Thermal Impedance vs. Pulse Width



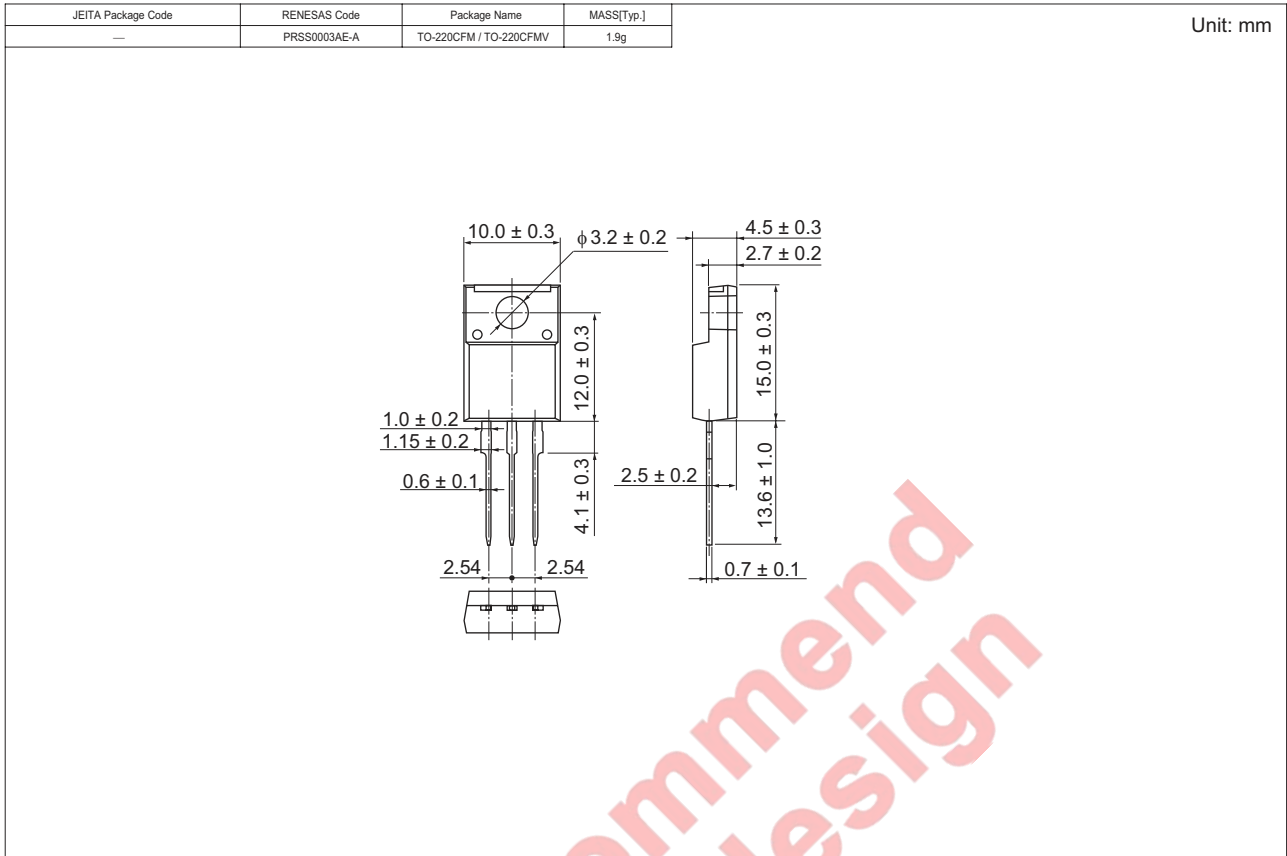
Switching Time Test Circuit



Waveform



Package Dimensions



Ordering Information

| Part Name | Quantity | Shipping Container |
|-----------|----------|--------------------|
| 2SK3234-E | 600 pcs | Box (Tube) |

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